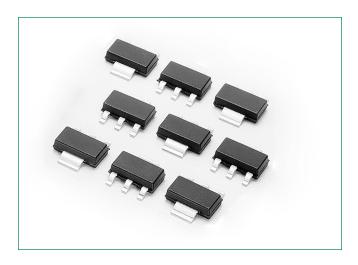


# NYC222, NYC226, NYC228





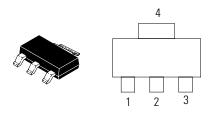
#### **Description**

Designed and tested for repetitive peak operation required for CD ignition, fuel ignitors, flash circuits, motor controls and low-power switching applications.

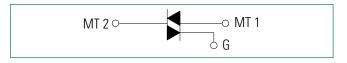
## **Features**

- Blocking Voltage to 600 V
- High Surge Current 15 A
- Very Low Forward "On" Voltage at High Current
- Low-Cost Surface Mount SOT–223 Package
- These are Pb-Free Devices

#### **Pin Out**



# **Functional Diagram**



# **Additional Information**







Samples



## **Maximum Ratings** $(T_1 = 25^{\circ}C \text{ unless otherwise noted})$

Rating	Symbol	Value	Unit	
Peak Repetitive Off–State Voltage (Note 1) $(R_{GK} = I_K, T_J - 40 \text{ to } +110^{\circ}\text{C}, \text{ Sine Wave, } 50 \text{ to } 60 \text{ Hz})$	V <sub>DRM</sub> , V <sub>RRM</sub>	50 400 600	V	
On-State RMS Current (180° Conduction Angles; T <sub>C</sub> = 80°C)		I <sub>T (RMS)</sub>	1.5	А
Average On-State Current, (T <sub>C</sub> = 65°C, f = 60 Hz, Time = 1 sec)		I <sub>T (RMS)</sub>	2.0	А
Peak Non-repetitive Surge Current, @T <sub>A</sub> = 25°C, (1/2 Cycle, Sine Wave, 60 Hz)	I <sub>TSM</sub>	15	А	
Circuit Fusing Considerations (t = 8.3 ms)		l²t	0.9	A2s
Forward Peak Gate Power (Pulse Width ≤ 1.0 sec, T <sub>A</sub> = 25°C)		P <sub>GM</sub>	0.5	W
Forward Average Gate Power (t = 8.3 msec, T <sub>A</sub> = 25°C)	P <sub>GM (AV)</sub>	0.1	W	
Forward Peak Gate Current (Pulse Width ≤ 1.0 s, T <sub>A</sub> = 25°C)	I <sub>FGM</sub>	0.2	А	
Reverse Peak Gate Voltage (Pulse Width $\leq$ 1.0 $\mu$ s, $T_A = 25$ °C)	$V_{RGM}$	5.0	V	
Operating Junction Temperature Range @ Rated V <sub>RRM</sub> and V <sub>DRM</sub>	T,	-40 to +110	°C	
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **Thermal Characteristics**

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient PCB Mounted	R <sub>8JA</sub>	156	mW
Thermal Resistance, Junction—to—Tab Measured on MT2 Tab Adjacent to Epoxy	R <sub>sut</sub>	25	°C/W
Maximum Device Temperature for Soldering Purposes for 10 Secs Maximum	T <sub>L</sub>	260	°C

# **Electrical Characteristics** - **OFF** ( $T_c = 25^{\circ}$ C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
†Peak Repetitive Blocking Current	T <sub>1</sub> = 25°C	I <sub>DRM</sub> ,	-	-	1.0	μΑ
$(V_{AK} = V_{DRM} = V_{RRM}; Gate Open)$	T <sub>J</sub> = 110°C	I <sub>RRM</sub>	-	-	200	mA

#### Electrical Characteristics - ON (T<sub>1</sub> = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Forward On-State Voltage (Note 2) (I <sub>TM</sub> = 2.2 A Peak)		V <sub>TM</sub>	-	1.2	1.7	V
HGate Trigger Current (Note 3)	$T_{\rm C} = 25^{\circ}{\rm C}$		_	30	200	
$(V_D = 12 \text{ V}, R_L = 100 \Omega, T_C = 25^{\circ}\text{C})$	T <sub>c</sub> =-40°C	C I <sub>GT</sub>	_	_	500	μΑ
Gate Trigger Voltage (dc) (Note 3)	$T_{\rm C} = 25^{\circ}{\rm C}$	\/	-	-	0.8	V
$(V_{AK} = 7 \text{ Vdc}, R_L = 100\Omega)$	T <sub>c</sub> =-40°C	V <sub>GT</sub>	-	_	1.2	V
Gate Non-Trigger Voltage $(V_{AK} = V_{DRM}, R_L = 100 \Omega)$	T <sub>C</sub> = 110°C	V <sub>GD</sub>	0.1	_	_	V
Holding Current	T <sub>C</sub> = 25°C		_	2.0	5.0	V
$(V_{AK} = 12 \text{ V}, R_{GK} = 1000 \Omega)$ Initiating Current = 200 mA	T <sub>C</sub> =-40°C	_	_	10	V	

<sup>1.</sup> V<sub>DRM</sub> and V<sub>BRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



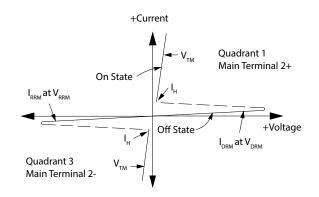
# **Dynamic Characteristics**

Characteristic	Symbol	Min	Тур	Max	Unit
Critical Rate-of-Rise of Off State Voltage (T <sub>c</sub> = 110°C)	dv/dt	-	25	_	V/µs
Critical Rate of Rise of On–State Current ( $T_C = 110$ °C, $I_G = 2 \times I_{GT}$ , $R_{GK} = 1 \text{ k}\Omega$ )	di/dt	-	20	_	A/μs

<sup>2.</sup> Pulse Width = 1.0 ms, Duty Cycle  $\leq 1\%$ .

# **Voltage Current Characteristic of SCR**

Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Forward Off State Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Reverse Off State Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Maximum On State Voltage
I <sub>H</sub>	Holding Current



<sup>3.</sup> RGK Current not included in measurement.



#### **Current Derating**

Figure 1. Maximum Case Temperature

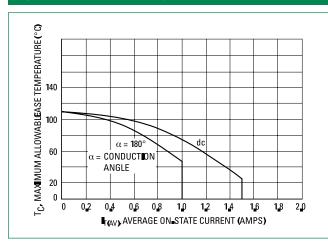


Figure 2. Maximum Ambient Temperature

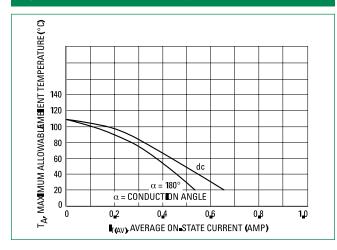
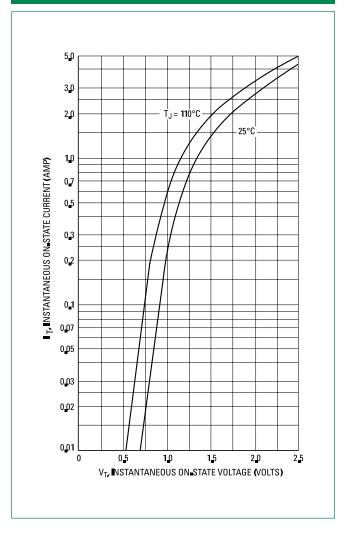
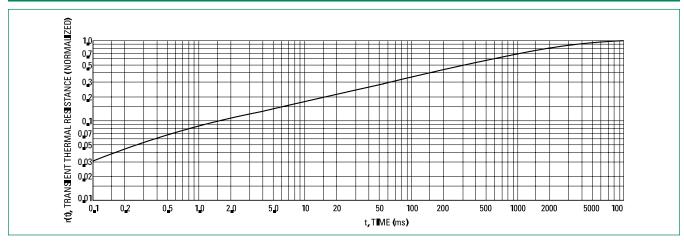


Figure 3. Typical Forward Voltage



**Figure 4. Thermal Response** 







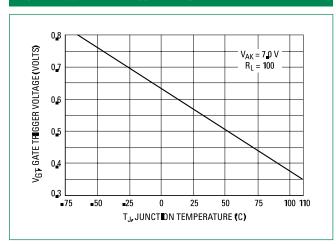
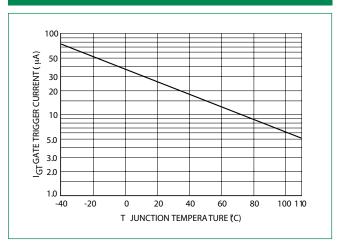


Figure 6. Typical Gate Trigger Current



**Figure 7. Typical Holding Current** 

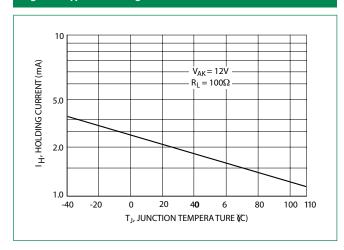
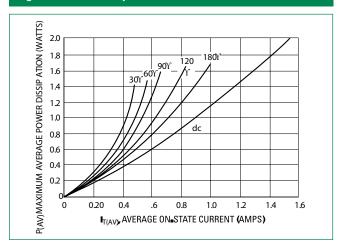
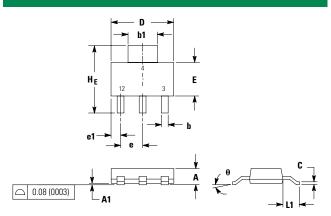


Figure 8. Power Dissipation





#### **Dimensions**



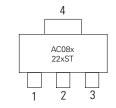
Dim	Inches		Millimet		ters	
Dilli	Min	Nom	Max	Min	Nom	Max
Α			0.071			1.80
A1	0.001	0.003	0.005	0.02	0.07	0.13
b	0.026	0.030	0.033	0.66	0.75	0.84
b1	0.114	0.118	0.122	2.90	3.00	3.10
С	0.009	0.011	0.014	0.23	0.29	0.35
D	0.260	0.260	0.264	6.60	6.60	6.71
E	0.130	0.138	0.146	3.30	3.50	3.70
е		0.091			2.30	
e1	0.030	0.037	0.045	0.75	0.95	1.15
L1	0.059	0.069	0.079	1.50	1.75	2.00
HE	0.268	0.276	0.283	6.80	7.00	7.20
ø	0°		10°	0°		10°

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

# **Part Marking System**



## SOT-223 Case 318E Style 11



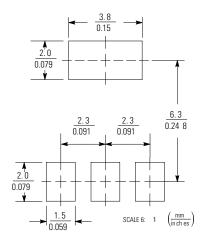
22xST =Device Code =D, M, or N

=Year Μ =Month

A XX G =Assembly Site

=Lot Serial Code =Pb-Free Package

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Pin Assignment				
1	Main Terminal 1			
2	Main Terminal 2			
3	Gate			
4	Main Terminal 2			

# **Ordering Information**

Device	Package	Shipping
NYC222STT1G	SOT-223 (Pb-Free)	
NYC226STT1G	SOT-223 (Pb-Free)	1000/Tape & Reel
NYC228STT1G	SOT-223 (Pb-Free)	

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